



60V 175°C NPN LOW SAT MEDIUM POWER TRANSISTOR IN POWERDI5060-8

Features

- BV_{CEO} > 60V
- I_C= 3A Continuous Collector Current
- I_{CM} = 8A Peak Pulse Current
- R_{CE(sat)} <90mΩ
- Rated to +175°C Ideal for High Ambient Temperature Environments
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN3C60PSQ is suitable for automotive applications requiring specific change control; it is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

PowerDI5060-8 (SWP) (Type Q)

<u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

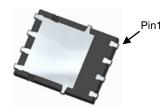
Applications

- Power Management
- Load Switch
- Linear Mode Voltage Regulator
- Backlighting Applications

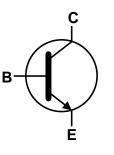


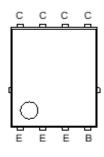
Top View

Notes:



Bottom View





Internal Schematic

Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN3C60PSQ-13	Automotive	DXTN3C60PS	13	12	2,500

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DXTN3 = Product Type Marking Code C60PS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Base Current	IB	500	mA
Continuous Collector Current	lc	3	A
Peak Pulse Collector Current	Ісм	8	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	2.5	W	
Thermal Desistance, Junction to Ambient	(Note 5)	P	60	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	140		
Thermal Resistance, Junction to Lead	(Note 7)	R _{θJL}	5.7	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

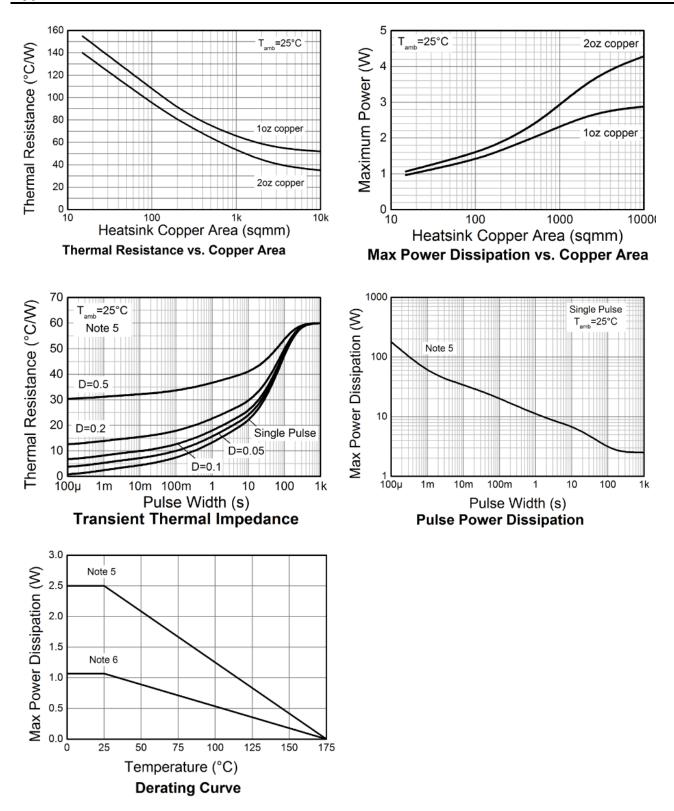
Notes: 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is

measured under still air conditions whilst operating in a steady-state. 6. Same as note (5), except mounted on minimum recommended pad layout.

Thermal resistance from junction to solder point (at the collector tab).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Typical Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)





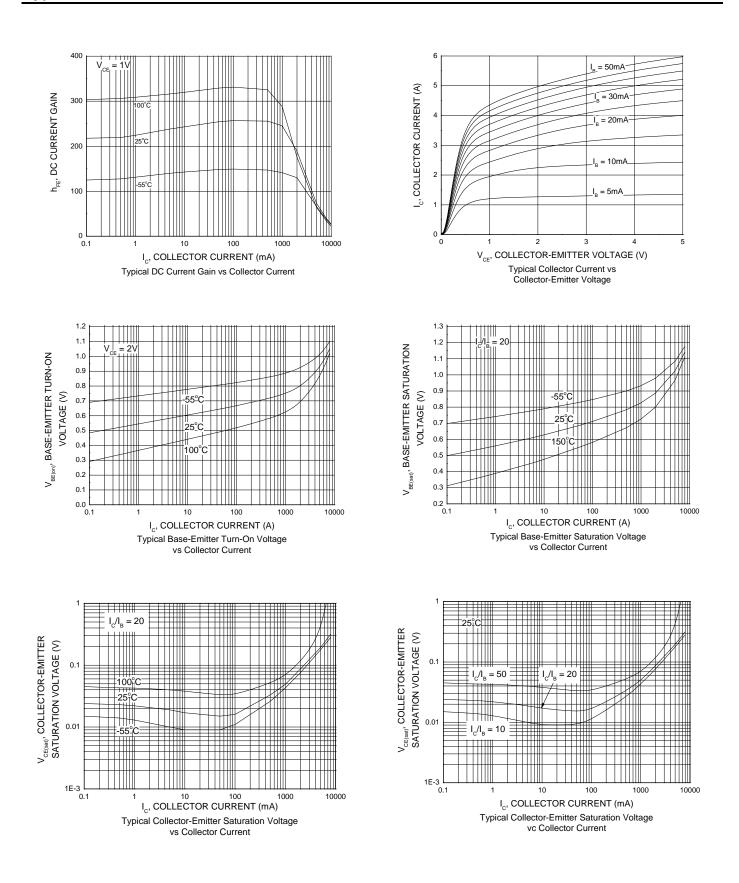
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BVCBO	60	_	—	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	_	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	—	V	I _E = 100μA
Collector-Base Cutoff Current		-	_	100	nA	$V_{CB} = 48V$
Collector-Base Cuton Current	I _{CBO}	-	_	50	μA	V _{CB} = 48V @T _J = +150°C
Emitter Cutoff Current	I _{EBO}	_	—	100	nA	V _{EB} = 7V
Collector-Emitter Cutoff Current	I _{CES}	-	_	100	nA	$V_{CES} = 48V$
ON CHARACTERISTICS (Note 9)						·
		200	400	—	_	$I_{C} = 500 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Gain	h	200	330	—		$I_C = 1A, V_{CE} = 2V$
DC Current Gam	hfe	100	180	—		$I_C = 2A, V_{CE} = 2V$
		50	100	—		$I_C = 3A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage	V	-	70	120	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA
	V _{CE(sat)}		180	270	mV	
Collector-Emitter Saturation Resistance	R _{CE(sat)}	—	60	90	mΩ	I _C = 3A, I _B = 300mA
Base-Emitter Saturation Voltage		—	0.86	1.0	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emilier Saturation voltage	V _{BE(sat)}	—	1.0	1.2	V	$I_{\rm C} = 2A, I_{\rm B} = 200 {\rm mA}$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	0.65	0.85	V	$I_{C} = 0.1A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						1
Current Gain-Bandwidth Product	f⊤	_	140	_	MHz	V _{CE} = 10V, I _C = 100mA, f = 10MHz
Output Capacitance	Cobo	_	17	_	pF	V _{CB} = 10V, f = 1MHz
Delay Time	t _d	_	15	_	ns	
Rise Time	tr	_	120	_	ns	
Turn-On Time	t _(on)	—	135	_	ns	V _{CC} = 12.5V, I _C = 1A
Storage Time	ts	_	800	—	ns	$I_{B1} = -I_{B2} = 0.05A$
Fall Time	t _f	—	300	_	ns]
Turn-Off Time	t _(off)		1100	_	ns]

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





PowerDI5060-8 (SWP)

(Type Q)

Min

0.90

0

0.30

0.20

3.56

3.78

5.60

3.46

1.05

0.025

3.205

10°

6°

Max

1.10

0.05

0.50

0.35

0.25REF

0.230 0.330 0.277

5.15 BS0

3.96

4.18

6.40 BSC

6.00

3.86

1.27BS0

0.200 0.400 0.300

0.050REF

0.225

4.005

12°

8°

4.70 5.10

4.195 4.595

0.635 0.835

0.635 0.835

All Dimensions in mm

Тур

1.00

0.41

0.25

4.90

3.76

3.98

5.80

3.66

4.395

0.735

0.735

0.125

3.605

11°

7°

Dim

Α

A1

b

b2

b4

С

D

D1

D2

D2a

Ε

E1

E2

E2a

е

k

L

La

L1

L1a

L4

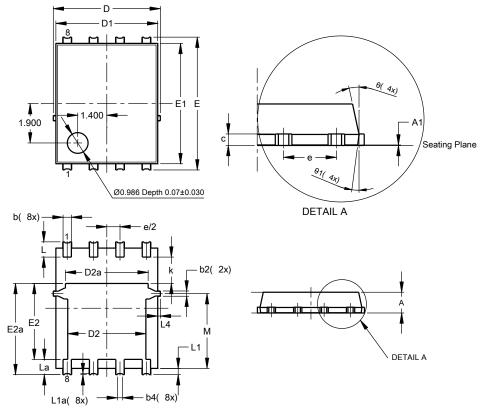
Μ

θ

θ1

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

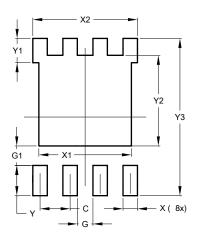


PowerDI5060-8 (SWP) (Type Q)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Ŷ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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